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Questions & Answers

deposited on silicon substrate **16** or formed by oxidizing the substrate in steam, for example. Layers **14** and **18** may be grown sequentially but are preferably grown simultaneously. Layer **18**, like layer **14** may be comprised of, e.g., undoped SiO_2 (silica), and may likewise have a thickness ranging from about 15-30 μm , but is also preferably about 15 μm .

[0022] A core layer may then be deposited on top of layer **18** using, e.g., standard silica deposition techniques such as flame hydrolysis or plasma-enhanced chemical vapor deposition (PECVD). This core material may be comprised of, e.g., silica with a dopant such as Germanium and/or Phosphorus, and may preferably have a refractive index about 0.5-1% higher than the lower cladding **18** index. Alternatively, the core material may comprise a variety of polymer materials such as optical grades of polyacrylates, polymethacrylates, polysilicone, polyimide, epoxy, polyurethane, polyolefin, polycarbonate, polyamides, polyesters, etc., as well as a various copolymers thereof, such as acrylate-methacrylates, acrylic-silicones, epoxy-urethanes, amide-imides, etc. The core layer may range in thickness, h , from about 5-8 μm , but is preferably about 6 μm thick. The core layer may be patterned using, e.g., photolithography and reactive ion etching, and an intermediate hard mask layer, such as chrome may be used, to define a waveguide core **20** preferably having a rectangular cross section. Waveguide core **20** also has a width, w , which may be varied accordingly to reduce the birefringence, as described below in detail.

[0023] After core **20** is etched, a silica top cladding layer **22** may be deposited on the structure. Although top cladding **22** may be comprised of specified compositions to reduce birefringence, as discussed above, this may be an unreliable method because of the difficulty in producing a top cladding composition which yields the required physical properties. A typical top cladding **22** may be comprised of, e.g., SiO_2 doped with Boron, but the concentration range of such dopants may be limited. For example, a top cladding **22** may be doped with, e.g., Boron, in a range of about 6-9% (wt.) because having a concentration of Boron below about 6% may yield glass which is too viscous for manufacturing and a concentration of Boron above about 9% may yield glass which crystallizes.

[0024] As part of the present invention, a table of illustrative material properties, i.e., elastic modulus, E, and coefficient of thermal expansion (CTE), are shown below in Table 1 for the purposes of discussion.

Table 1. Example of material properties in a variation of a waveguide.

Waveguide element	E (GPa)	CTE ($\times 10^{-6} \text{ }^{\circ}\text{C}^{-1}$)
Top cladding	44	*
Waveguide core	62	2
Silicon (substrate)	200	3.5
Undoped SiO ₂	70	1

* Discussed below.

[0025] During the manufacture of an AWG, the layers of material are typically produced at elevated temperatures or they may require high temperature treatment to ensure homogeneity. Processing temperatures may be as high as about 900° C. Upon cooling, stresses may become induced into the waveguide core 20 because of the differing CTE values between, e.g., layer 18 and top cladding 22, thereby resulting in undesired birefringence in light carried through core 20. According to the invention, varying the width, w, of the waveguide core 20 may be selected to reduce or eliminate birefringence for a given tuned top cladding 22 having a pre-existing dopant concentration. The CTE mismatch from ambient temperature to a device operating temperature may typically be ignored for the purposes of the present invention because of the minimal effect such a temperature change may have.

[0026] In calculating an optimal width for birefringence reduction for a given top cladding 22, a stress value may be induced within core 20 in its blanket form. This stress value is typically due to a CTE mismatch between the film and the substrate and may result in a curvature within the plane of the substrate. This curvature may be measured and from there, the stress in the core film may be calculated by the following equation (1):

$$\sigma_{core} = \frac{E_{sub}(t_{sub})^2}{6Rt_{core}} \quad (1)$$

where,

σ_{core} = stress value induced in core 20 by a curvature of substrate 16;

E_{sub} = elastic modulus of the substrate 16;

t_{sub} = substrate thickness;

R = radius of curvature of a given wafer from which a device may be manufactured from according to the present invention;

t_{core} = waveguide core 20 thickness, h.

[0027] In one variation, an example using the values as illustrated in Table 1 and $t_{sub} = 625 \mu m$ in equation (1) may yield the following in equation (2):

$$\sigma_{core} = \frac{(200 \times 10^9)(625 \times 10^{-6})^2}{6(-22)(6 \times 10^{-6})} = -98 MPa \quad (2)$$

[0028] Once calculated, the value of σ_{core} may be substituted into the following equation (3) to calculate the CTE value, α_{core} , of core 20:

$$\alpha_{core} = \alpha_{sub} - \frac{\sigma_{core}}{E_{core}(\Delta T)} \quad (3)$$

where,

α_{core} = calculated CTE of core 20;

α_{sub} = CTE of substrate 16;

E_{core} = elastic modulus of core 20;

ΔT = temperature range through which the materials undergo.

[0029] Substituting the values from equation (2) and Table 1 may yield the following equation (4):

$$\begin{aligned} \alpha_{core} &= (3.5 \times 10^{-6}) - \frac{-98 \times 10^6}{(62 \times 10^9)(-900)} \\ &= 1.74 \times 10^{-6} \cong 2.0 \times 10^{-6} ^\circ C^{-1} \end{aligned} \quad (4)$$

These calculations may be performed for each individual layer within cross-section 10 to obtain the stress and CTE values of each layer.

[0030] A stress value of top cladding 22 induced by CTE differences over the temperature range ΔT , e.g., about 900° C from manufacturing/processing temperature to ambient temperature, may also be calculated. As discussed above, if top cladding 22 were doped with a high concentration, e.g., about 9% (wt.) of Boron, a tensile stress may be induced in top cladding 22; on the other hand, if top cladding 22 were doped with a low concentration, e.g., about 6% (wt.) of Boron, a compressive stress or zero load may be induced in top cladding 22. In calculating the stress, the following equation (5) may be used:

$$\sigma_{tc} = E_{tc} (-\alpha_{tc} + \alpha_{sub}) (\Delta T) \quad (5)$$

where,

σ_{tc} = stress value induced in top cladding 22 by CTE differences between top cladding 22 and substrate 16;

α_{tc} = CTE of top cladding 22;

α_{sub} = CTE of substrate 16;

E_{tc} = elastic modulus of top cladding 22;

ΔT = temperature range through which the materials undergo.

[0031] Substituting in values from Table 1 for a variation where a top cladding 22 has a CTE of about, e.g., $\alpha_{tc} = 3.2 \times 10^{-6} \text{ } ^\circ\text{C}^{-1}$, and undergoes a temperature change of about, e.g., $\Delta T = 900^\circ \text{C}$, may yield the following equation (6). Whereas, top cladding 22 having a CTE of about, e.g., $\alpha_{tc} = 4.0 \times 10^{-6} \text{ } ^\circ\text{C}^{-1}$, may yield the following equation (7).

$$\sigma_{tc} = (44 \times 10^9)(-3.2 + 3.5)(-900)(\times 10^{-6}) = -12 \text{ MPa} \quad (6)$$

$$\sigma_{tc} = (44 \times 10^9)(-4.0 + 3.5)(-900)(\times 10^{-6}) = 20 \text{ MPa} \quad (7)$$

[0032] As discussed above, a difference in effective index for the TE and TM polarization states is a reason for the occurrence of PDW, as expressed in equation (8):

$$PDW = \lambda_{c(TM)} - \lambda_{c(TE)} \quad (8)$$

where,

$$\lambda_c = \beta \frac{\Delta L}{m} \quad (9)$$

λ_c = wavelength of light through waveguide core 20;

β = effective refractive index;

ΔL = distance traveled by the light through waveguide core 20;

m = diffraction order.

Substituting equation (9) into equation (8) yields the following result in equation (10):

$$PDW = (\beta_{TM} - \beta_{TE}) \frac{\Delta L}{m} \quad (10)$$

[0033] The difference between β_{TM} and β_{TE} may be a result of differing stresses in the x- and y-directions along waveguide core 20. This difference may vary as the width, w , of core 20 varies. As seen in Fig. 2 in chart 30, stress (in MPa) induced in top cladding 22 may be plotted against core width (in μm) to see the relationship. Curve 32 represents the increasing absolute value of stress, σ_x , along the x-axis as the width, w , of core 20 increases. On the other hand, curve 34 shows a decreasing stress state, σ_y , along the y-axis as the width of core 20 increases. The overall stress state between σ_x and σ_y is shown in curve 36, where the stress state is shown to increase as core width increases.

[0034] In practice, stress calculations and stress distributions may be complex and are preferably solved through the use of computer simulations, e.g., finite element modeling/analysis, which may account for geometry, differences in material properties, and external factors such as temperature changes and forces. Given the different CTE and stress values for each of the layers, as described

above, the stress distributions may be calculated over a range of varying core **20** widths, w , e.g., widths up to $11\ \mu\text{m}$ and up. That is, thermal stress distributions in waveguide core **20** and surrounding cladding **22** may be calculated for each core **20** width over a range of widths.

[0035] Once the stress distributions are calculated, as described above, an index distribution may be calculated according to the following equations (11) and (12):

$$n_y(x,y) = n_{y0}(x,y) - c_1\sigma_y(x,y) - c_2[\sigma_z(x,y) + \sigma_x(x,y)] \quad (11)$$

$$n_x(x,y) = n_{x0}(x,y) - c_1\sigma_x(x,y) - c_2[\sigma_y(x,y) + \sigma_z(x,y)] \quad (12)$$

Constants c_1 and c_2 are stress optic coefficients where, e.g., $c_1 = 7.56 \times 10^{-7}\ \text{MPa}^{-1}$ and $c_2 = 4.18 \times 10^{-6}\ \text{MPa}^{-1}$; and where, e.g., $n_{x0} = n_{y0} = 1.4455$ for top clad **22** and $n_{x0} = n_{y0} = 1.455$ for core **20**.

[0036] Properties such as refractive index can have complex distributions throughout a device and may be solved through computer simulation of the geometry, refractive indices, and absorption of the waveguide and cladding, as well as index change mechanisms, e.g. temperature changes, using commonly available photonic software such as BeamPROP, made by RSoft, Inc. of Ossining, NY. From such software tools and from the stress results and stress distributions, the effective refractive index may be found. With the results of refractive index distribution according to equations (11) and (12), the effective refractive index β may be calculated using, e.g., the BeamPROP simulation. This may be performed at least once for the TE mode (n_x distribution) and at least once for the TM mode (n_y distribution). Once the results of β_{TM} and β_{TE} have been calculated, PDW may finally be calculated with equation (10).

[0037] An example of another method of PDW reduction which varies the lengths of the relevant waveguides as well as utilizes the results of β_{TM} and β_{TE} may be found in the commonly-assigned U.S. Patent Application entitled "Arrayed Waveguide Grating With Waveguides Of Unequal Widths" to Kenneth

McGreer, filed on May 30, 2001 and which is incorporated herein by reference in its entirety.

[0038] Fig. 3 illustrates the relationship in chart 40 between PDW (in nm) and core width (in μm) for a top cladding having several different CTE values. Curve 42 represents a variation where a top cladding 22 has a CTE of about $4.0 \times 10^{-6} \text{ }^\circ\text{C}^{-1}$ and a resulting σ_{tc} equal to about 20 MPa for a ΔT of about 900°C . Curve 46 represents another variation where top cladding 22 CTE is about $3.6 \times 10^{-6} \text{ }^\circ\text{C}^{-1}$ and a resulting σ_{tc} equal to about 4 MPa. Likewise, curve 48 represents yet another variation where the CTE of top cladding 22 is about $3.2 \times 10^{-6} \text{ }^\circ\text{C}^{-1}$ and a resulting σ_{tc} equal to about -12 MPa. As seen, as top cladding 22 CTE is lowered below that of substrate 16 (where CTE is about $3.5 \times 10^{-6} \text{ }^\circ\text{C}^{-1}$ in this variation), PDW generally increases. Data points 44 represent experimental results and are shown to show the close approximation and validity of the methods described above.

[0039] Boundary 50 represents a state where PDW is zero. Accordingly, for every top cladding 22 process, e.g., a high Boron concentration and high CTE or a low Boron concentration and low CTE, a corresponding width, w , for waveguide core 20, such as the width corresponding to intersection 52, may be found that results in a zero PDW state.

[0040] As described above, in calculating a width of a waveguide core that provides a desired birefringence for a given tuned top cladding composition, the distribution of stress in a top cladding over a change in temperature may be determined. From the distribution of stress, a relationship may be determined between polarization dependent wavelength and a width of the waveguide in the arrayed waveguide grating. From this relationship, the width of the waveguide may be selected such that the polarization dependent wavelength is minimized or reduced to a desired value to compensate for birefringence.

[0041] A flow chart 60 is shown in Fig. 4 for one variation on a method of determining waveguide width for a given top cladding. Operation 62 may begin by determining an elastic modulus of each of the constituent layers, e.g., layers 14 to 22. This may be accomplished by measuring the modulus directly. Operation

